Very Low Forward Voltage Trench-based Schottky Rectifier

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free and Halide–Free Devices

Mechanical Characteristics:

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 11.7 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds
- MSL 1

Typical Applications

- Switching Power Supplies including Compact Adapters and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation
- Automotive LED Lighting



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TRENCH SCHOTTKY RECTIFIER 2.0 AMPERES 45 VOLTS



SOD-123FL CASE 498 PLASTIC

MARKING DIAGRAM



2AE = Specific Device Code M = Date Code • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NRVTS245ESFT1G	SOD-123 (Pb-Free)	3,000/ Tape & Reel
NRVTS245ESFT3G	SOD-123 (Pb-Free)	10,000/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating		Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V	
Average Rectified Forward Current $(T_L = 148^{\circ}C)$	lo	2.0	A	
Peak Repetitive Forward Current (Square Wave, 20 kHz, T _L = 143°C)	I _{FRM}	4.0	A	
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	50	A	
Storage and Operating Junction Temperature Range (Note 1)	T _{stg} , T _J	-65 to +175	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from

Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Characteristic		Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2)	Ψ_{JCL}	23	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	R_{\thetaJA}	85	°C/W
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	330	°C/W

ELECTRICAL CHARACTERISTICS

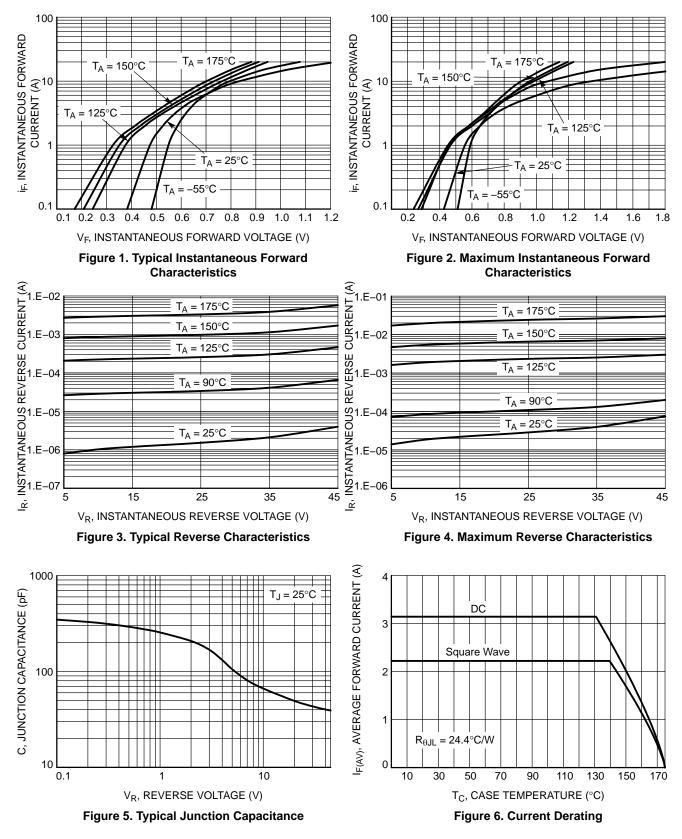
Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 4) $(I_F = 2.0 \text{ A}, T_J = 25^{\circ}\text{C})$ $(I_F = 2.0 \text{ A}, T_J = 125^{\circ}\text{C})$	V _F	0.65 0.58	V
Maximum Instantaneous Reverse Current (Note 4) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)	I _R	75 3	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

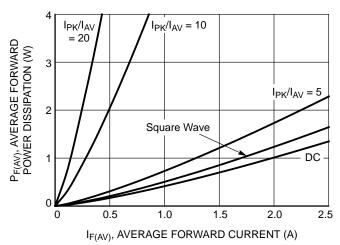
2. Mounted with 700 mm² copper pad size (Approximately 1 in²) 1 oz FR4 Board.

3. Mounted with pad size approximately 20 mm² copper, 1 oz FR4 Board. 4. Pulse Test: Pulse Width \leq 380 µs, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





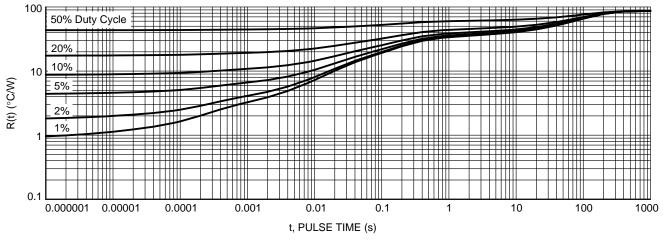


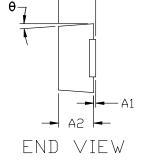
Figure 8. Thermal Characteristics

SOD-123-2 1.65x2.70x0.90 F D 2 1

TOP VIEW

— Н_Е

SIDE VIEW



	MILLIMETERS		
DIM	MIN.	NDM.	MAX.
А	0.90	0.95	0.98
A1	0.00	0.05	0.10
A2	0.85	0.90	0.95
Q	0.70	0.90	1.10
С	0.10	0.15	0.20
D	1.50	1.65	1.80
E	2.50	2.70	2.90
E1	1.70	2.10	2.50
Η _E	3.40	3.60	3.80
L	0.55	0.75	0.95
θ	0°		8•

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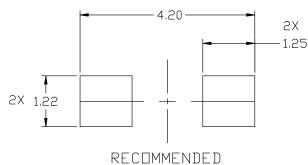
DATE 22 AUG 2023

NDTES:

С

-2X L

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSIONS 6 AND L ARE TO BE MEASURED ON A З. FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.25 FROM THE LEAD TIP.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH PROTRUSIONS, OR GATE BURRS.
- 5. FLAT LEAD.



MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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GENERIC **MARKING DIAGRAM***

-E1-BOTTOM VIEW



XXX = Specific Device Code = Date Code Μ

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

А

CASE 498 ISSUE E

2X b

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